

Description

The AP3785T is a high performance AC/DC power supply controller for battery charger and adapter applications. It can meet less than 10mW standby power for "Super Star" charger criteria. The device uses Pulse Frequency Modulation (PFM) method to build discontinuous conduction mode (DCM) flyback power supplies.

The AP3785T provides accurate constant voltage (CV), constant current (CC) and outstanding dynamic performance without requiring an opto-coupler. It also eliminates the need of loop compensation circuitry while maintaining stability.

The AP3785T is equipped with both cable drop compensation function to meet various cables with different lengths and gauges and adjustable line voltage compensation function.

When AP3785T is used with AP4341 or synchronous rectifier series (for example APR343 + MOSFET, APR3415, APR34330), better under-shoot performance and higher conversion efficiency can be achieved.

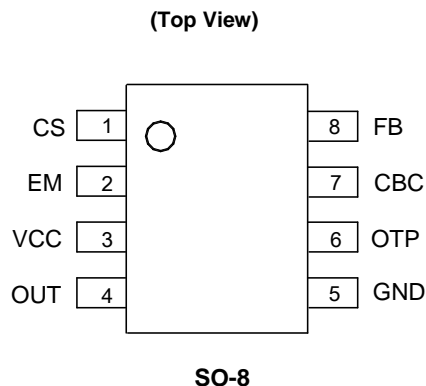
The AP3785T has internal over temperature protection for itself, and also provides dedicated pin for external over temperature protection.

This IC is available in SO-8 package.

Applications

- Adapter/Chargers for Shaver, Cell/Cordless Phones, PDAs, MP3 and Other Portable Apparatus
- Standby and Auxiliary Power Supplies

Pin Assignments



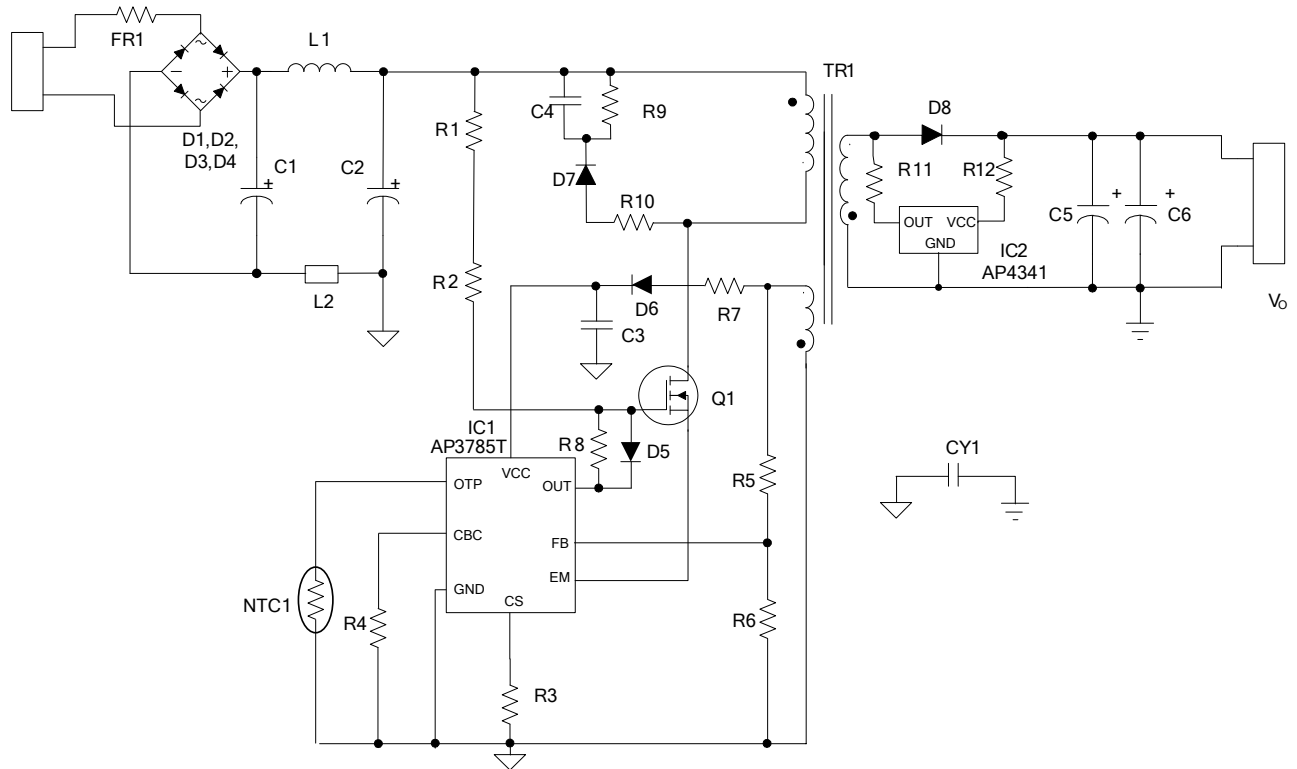
Features

- Primary Side Control for Eliminating Opto-coupler
- 10mW No-load Input Power
- Flyback Topology in DCM Operation
- External Adjustable Line Compensation for CC
- External Adjustable Cable Compensation for CV
- Multiple PWM/PFM Control Mode to Improve Audio Noise and Efficiency
- V_{CS} Jitter to Reduce System EMI
- Valley-on for the Higher Efficiency and Better EMI
- Multiple Protections:
 - Over Voltage Protection (OVP)
 - Output Short Circuit Protection (SCP)
 - Transformer Saturation Protection (TSP) via Primary Peak Current Limitation
 - OTP and External Over Temperature Protection (OTP)
- Matching AP4341 with Schottky or APR343/APR3415 Synchronous Rectifier Solution
- SO-8 Package
- **Totally Lead-free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

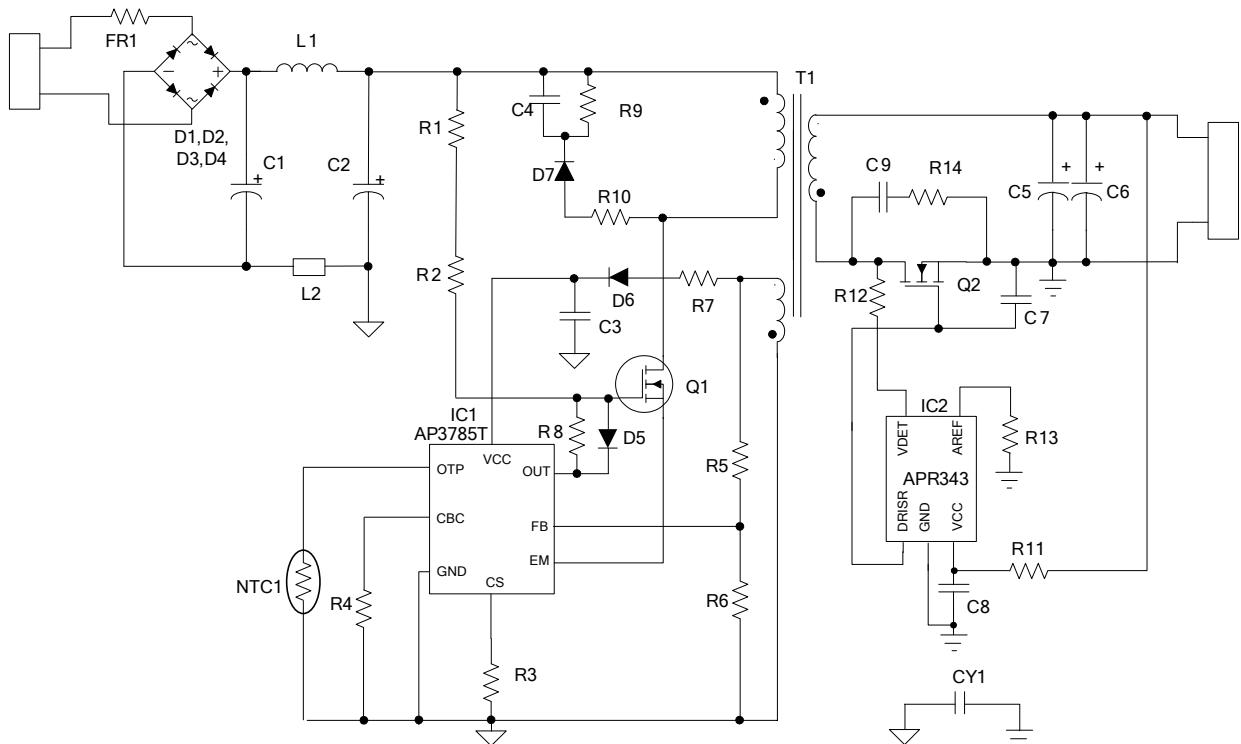
Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Typical Applications Circuit (Note 4)

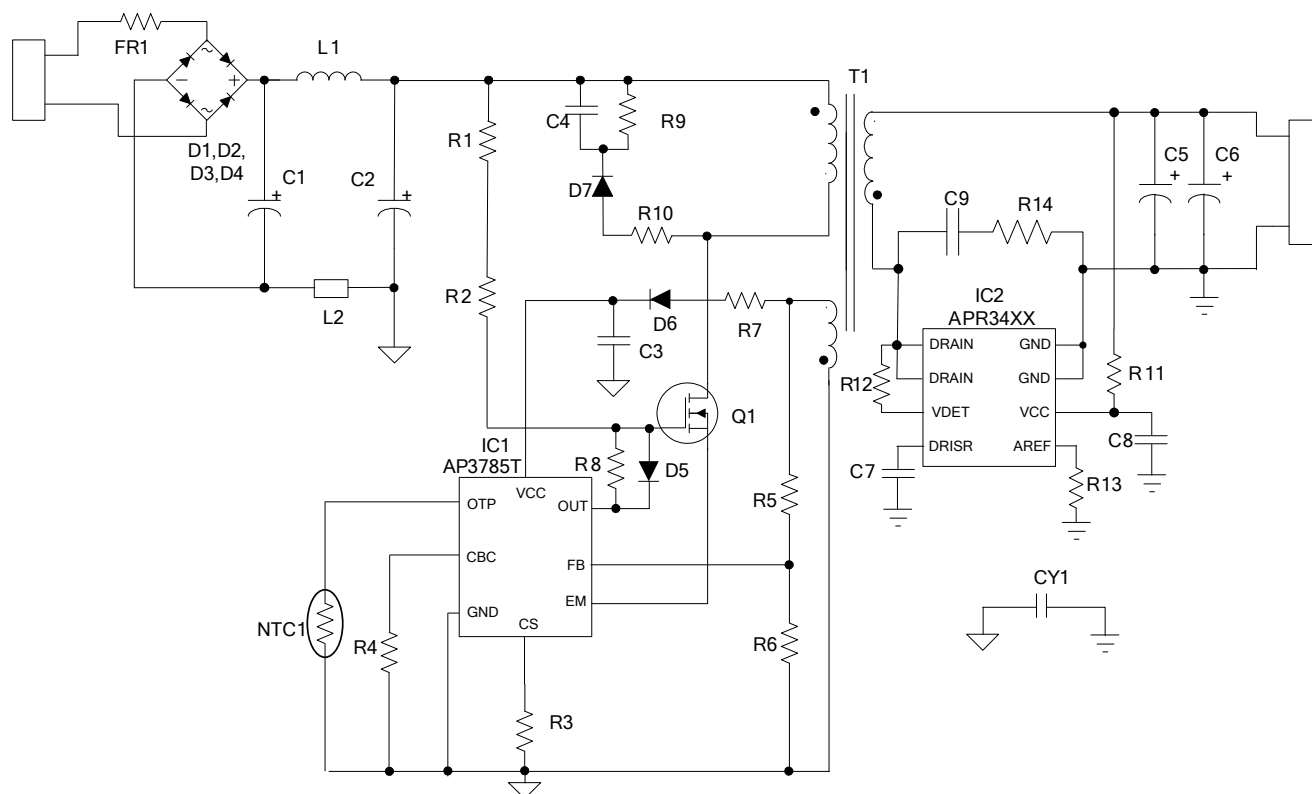


With Schottky ($V_{OUT}=5V/1A$ or $2A$)



With Synchronous Rectifier ($V_{OUT}=5V/2A$)

Typical Applications Circuit (Note 4, Cont.)



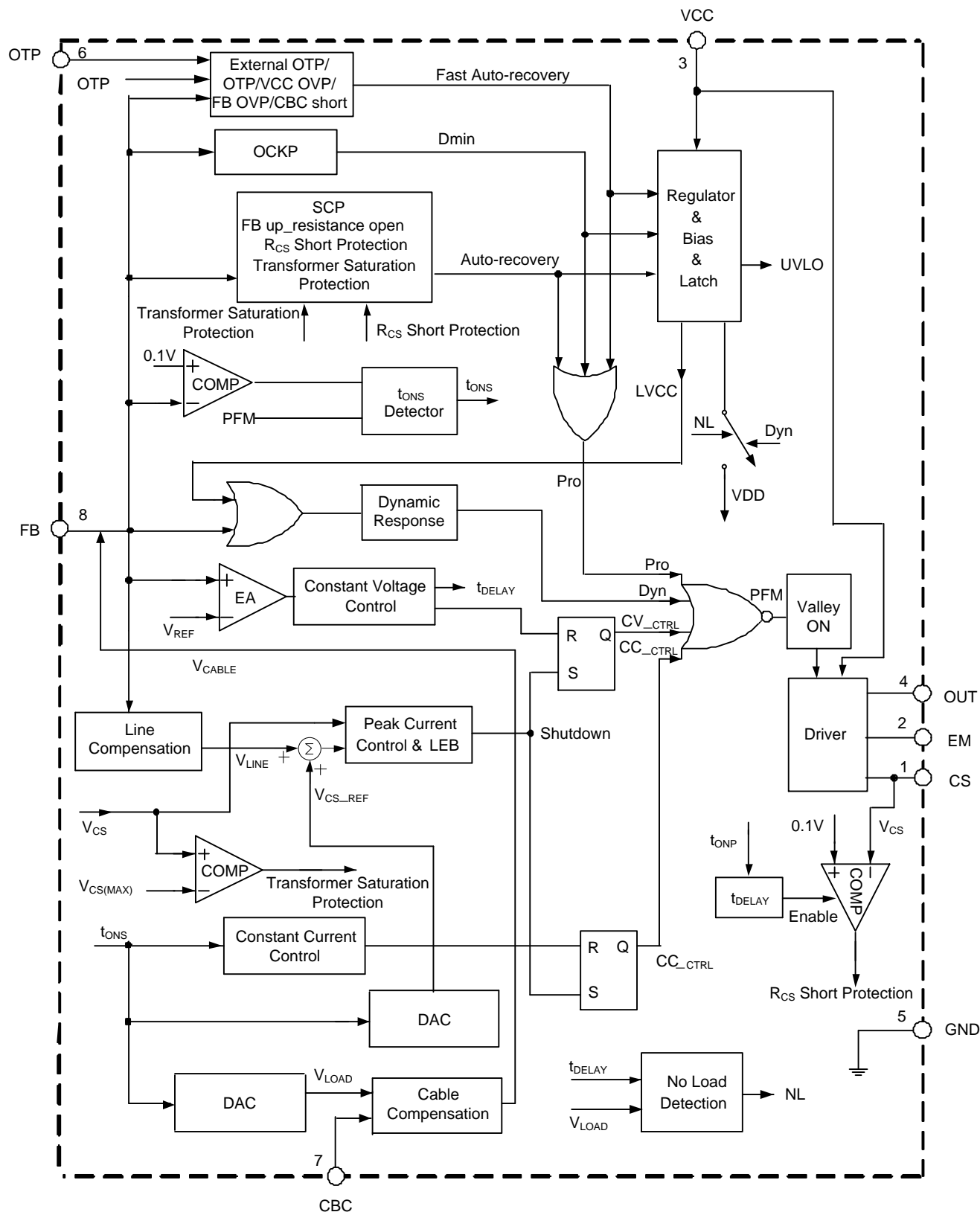
With Synchronous Rectifier (i.e. APR34330 for $V_{OUT}=5V/1.5A$, APR3415 for $V_{OUT}=5V/2A$ and APR34309 for $V_{OUT}=5V/3A$)

Note 4: If the OTP pin is not connected to the NTC resistor, the external OTP function will not work and the IC can still work normally with internal OTP.

Pin Descriptions

Pin Number	Pin Name	Function
1	CS	Sense primary side current for turning off the external power MOSFET and deliver a voltage proportional to the line voltage for compensation from FB pin
2	EM	Connected to the source of external power MOSFET
3	VCC	The power supply for the IC. In order to get the correct operation of the IC, a capacitor with low ESR should be placed as close as possible to the VCC pin
4	OUT	Turn on and turn off the external power MOSFET
5	GND	The ground of the IC
6	OTP	The external over temperature protection
7	CBC	This pin connects a resistor to GND for output cable voltage drop compensation
8	FB	Voltage feedback. The CV and CC regulation are realized based on the voltage sampling of this pin

Functional Block Diagram



Absolute Maximum Ratings (Note 5)

Symbol	Parameter	Rating	Unit
V_{CC}	Voltage at VCC to GND	-0.3 to 30	V
–	Voltage at OUT, EM to GND	-0.3 to 22	V
–	Voltage at CS, CBC,OTP to GND	-0.3 to 7.4	V
V_{FB}	FB Input Voltage	-0.7 to 7.4	V
T_J	Operating Junction Temperature	-40 to +150	°C
T_{STG}	Storage Temperature	-65 to +150	°C
T_{LEAD}	Lead Temperature (Soldering, 10 sec)	+300	°C
θ_{JC}	Thermal Resistance (Junction to Case)	20	°C/W
θ_{JA}	Thermal Resistance (Junction to Ambient) (Note 6)	100	°C/W
–	ESD (Human Body Model)	4000	V
–	ESD (Machine Model)	200	V

Notes: 5. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

6. The device is mounted on FR-4 substrate PCB, 2 oz copper, with 1 inch² pad.

Electrical Characteristics (@ $V_{CC}=15V$, $T_A=+25^{\circ}C$, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
STARTUP AND UVLO SECTION						
V _{TH_ST}	Startup Threshold	–	11	13	15	V
V _{OPR(MIN)}	Minimum Operating Voltage	–	5.5	5.9	6.3	V
STANDBY CURRENT SECTION						
I _{ST}	Startup Current	V _{CC} =V _{TH_ST} -1V before startup	0	0.2	0.6	μA
I _{CC_NL}	Standby Current	At no load	5	17.5	30	
I _{CC_OPR}	Operating Current	Static current	350	450	550	
DRIVING OUTPUT SECTION						
V _{GATE}	Gate Voltage	–	9	10.5	12	V
I _{SOURCE_PEAK}	Peak Driver Source Current	–	15	20.5	26	mA
R _{DS(ON)}	Sink Resistance	–	2	2.3	2.6	Ω

Electrical Characteristics (Cont.) (@V_{CC}=15V, T_A=+25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
OPERATING FREQUENCY SECTION (NL MODE TO FULL LOAD)						
f _{S(MAX)}	The Maximum Operating Frequency	100% full load	–	–	80	kHz
t _{sample_H}	Sample Time	40% to 100% full load	4.8	5.2	5.7	μs
t _{sample_L}		NL Mode to 8% full load	2.4	2.7	3.0	μs
OPERATING FREQUENCY SECTION (NL MODE)						
V _{CBC(EN)}	CBC Pin Voltage to Enter NL Mode	–	55	60	65	mV
t _{OFF(EN)}	Off Time to Enter NL Mode	From the end of t _{ONS}	168	224	280	μs
t _{OFF(EX)}	Off Time to Exit NL Mode	From the end of t _{ONS}	168	224	280	μs
FREQUENCY JITTER						
ΔV _{CS} /V _{CS}	V _{CS} Modulation	NL to full load	4.5	5	5.5	%
f _{MOD}	V _{CS} Modulation Frequency		1.8	2	2.2	kHz
CURRENT SENSE SECTION						
V _{CS_H}	Peak Current Sense Threshold Voltage	40% to 100% full load	537	565	593	mV
V _{CS_L}		0% to 8% full load	243	255	267	mV
R _{LINE}	Built-in Line Compensation Resistor	(Note 8)	108	120	132	Ω
t _{LEB}	Leading Edge Blanking	–	400	625	850	ns
CONSTANT VOLTAGE SECTION						
V _{FB}	Feedback Threshold Voltage	Closed loop test of V _{OUT}	2.45	2.50	2.55	V
V _{CBC(MAX)}	Maximum CBC Voltage for Cable Compensation	–	1.4	1.45	1.5	V
CONSTANT CURRENT SECTION						
t _{ONS} /t _{SW}	Secondary Winding Conduction Duty	Tested @ V _{FB} =2V	–	4/8	–	–
VALLEY-ON SECTION						
t _{VAL-ON}	Valid Off Time of Valley-on	From the end of t _{ONS}	20	27	34	μs
DYNAMIC SECTION						
V _{TRIGGER}	Trigger Voltage for Dynamic Function	–	40	62.5	85	mV
t _{DELAY}	Delay Time for Dynamic Function	From the end of t _{ONS}	99	127	155	μs
V _{UV_H}	Under Voltage of FB Pin for V _{CS_H}	–	2.23	2.27	2.32	V
PROTECTION FUNCTION SECTION						
V _{FB(OVP)}	Over Voltage Protection at FB Pin	–	3.5	3.75	4	V
V _{CC(OVP)}	Over Voltage Protection at VCC Pin	–	27	28.5	30	V
t _{ONP(MAX)}	Maximum Turn-on Time	–	14	18	22	μs
t _{OFF(MAX)}	Maximum Off Time	–	11	14	17	ms

Notes:

- These parameters are not 100% tested, guaranteed by design and characterization.
- Line compensation voltage on CS reference: $\Delta V_{CS_REF} = 0.35 \times \frac{R_{LINE}}{R_{FR1} + R_{INF}} \times V_{AUX}$

1. Start-up Circuit



- Before V_{CC} reaches $V_{TH(ST)}$, V_{DD} is zero and EM to CS pin is open.
- C3 is charged by I_{SOURCE} .
- The resistance of R13 and R15 should be high enough to reduce the power dissipation.

Operation Principle Description (Cont.)

Figure 1 (b) shows the Normal Operation Phase

- When V_{CC} reaches $V_{TH(ST)}$, V_{DD} is high and EM to CS pin is short.
- The voltage of EM pin is lower than 1V so that the four diodes in chip are open.
- C3 is supplied by Aux. winding of transformer.

2. Operation Mode

The typical application circuit of AP3785T is a conventional Flyback converter with a 3-winding transformer---primary winding (N_P), secondary winding (N_S) and auxiliary winding (N_{AUX}), as shown in typical application with AP4341. The auxiliary winding is used for providing VCC supply voltage for IC and sensing the output voltage feedback signal to FB pin.

Figure 2 shows the typical waveforms which demonstrate the basic operating principle of AP3785T application. And the parameters are defined as following.

- I_P ---The primary side current
- I_S ---The secondary side current
- I_{PK} ---Peak value of primary side current
- I_{PKS} ---Peak value of secondary side current
- V_{SEC} ---The transient voltage at secondary winding
- V_S ---The stable voltage at secondary winding when rectification diode is in conducting status, which equals the sum of output voltage V_O and the forward voltage drop of diode
- V_{AUX} ---The transient voltage at auxiliary winding
- V_A --- The stable voltage at auxiliary winding when rectification diode is in conducting status, which equals the sum of voltage V_{CC} and the forward voltage drop of auxiliary diode
- t_{SW} ---The period of switching frequency
- t_{ONP} ---The conduction time when primary side switch is "ON"
- t_{ONS} ---The conduction time when secondary side diode is "ON"
- t_{OFF} ---The dead time when neither primary side switch nor secondary side diode is "ON"
- t_{OFFS} --- The time when secondary side diode is "OFF"

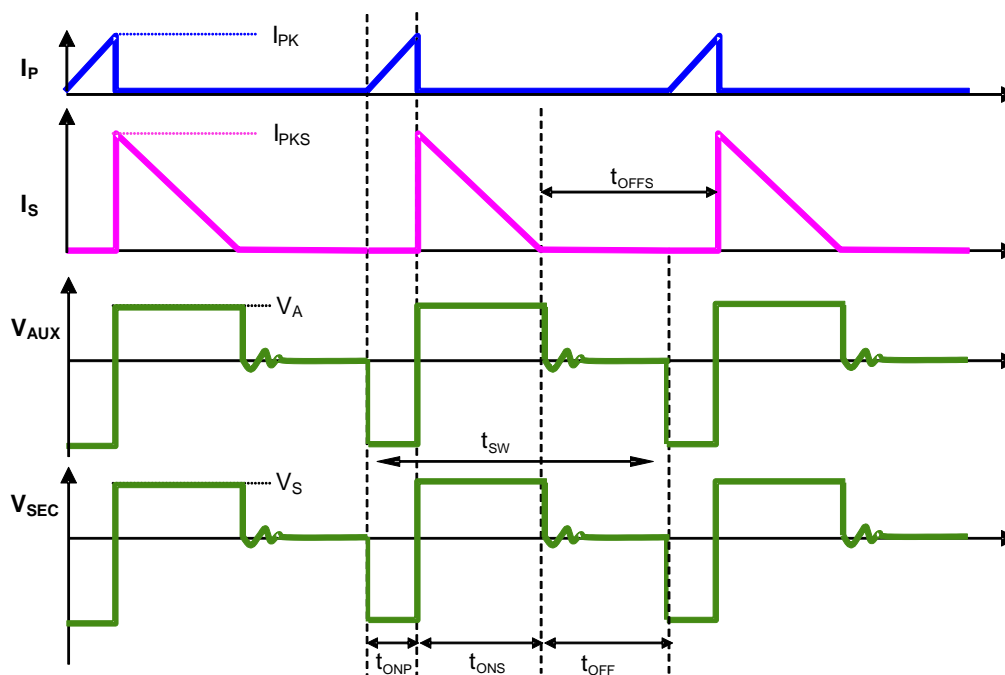


Figure 2. The Operation Waveform of Flyback PSR System

Operation Principle Description (Cont.)

3. Constant Voltage Operation

As to constant-voltage (CV) operation mode, the AP3785T detects the auxiliary winding voltage at FB pin to regulate the output voltage. The auxiliary winding voltage is coupled with secondary side winding voltage, so the auxiliary winding voltage during the conduction time of secondary rectification diode D1 is:

$$V_{AUX} = \frac{N_{AUX}}{N_S} \times (V_{OUT} + V_d) \quad (1)$$

Where V_d is the diode forward voltage drop.

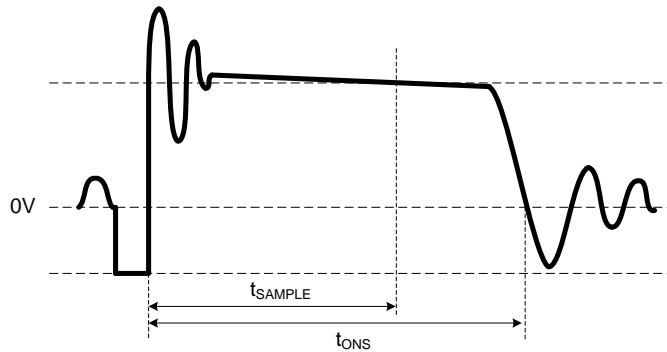


Figure 3. Auxiliary Voltage Waveform

The voltage detection point is at the t_{SAMPLE} of the D1 on-time. The voltage detection point is changed with the different primary peak current. The CV loop control function of AP3785T then generates a D1 off-time to regulate the output voltage.

4. Constant Current Operation

The AP3785T can work in constant-current (CC) mode. Figure 2 shows the secondary current waveforms.

In CC operation mode, the CC control loop of AP3785T will keep a fixed proportion between D1 on-time t_{ONS} and D1 off-time t_{OFFS} . The fixed proportion is

$$\frac{t_{ONS}}{t_{OFFS}} = \frac{4}{4} \quad (2)$$

The relationship between the output current and secondary peak current I_{PKS} is given by:

$$I_{OUT} = \frac{1}{2} \times I_{PKS} \times \frac{t_{ONS}}{t_{ONS} + t_{OFFS}} \quad (3)$$

As to tight coupled primary and secondary winding, the secondary peak current is

$$I_{PKS} = \frac{N_P}{N_S} \times I_{PK} \quad (4)$$

Thus the output constant-current is given by:

$$I_{OUT} = \frac{1}{2} \times \frac{N_P}{N_S} \times I_{PK} \times \frac{t_{ONS}}{t_{ONS} + t_{OFFS}} = \frac{2}{8} \times \frac{N_P}{N_S} \times I_{PK} \quad (5)$$

Therefore, AP3785T can realize CC mode operation by constant primary peak current and fixed diode conduction duty cycle.

Operation Principle Description (Cont.)

5. Multiple Segment Peak Current

As to the original PFM PSR system, the switching frequency decreases with decreasing of output current, which will encounter audible noise issue since switching frequency decreases to audio frequency range, about less than 20kHz.

In order to avoid audible noise issue, AP3785T uses 3-segment primary peak current control method at constant voltage (CV) mode, the current sense threshold voltage is multiple segments with different loading, as shown in Figure 4, which are V_{CS_H} for high load, varied V_{CS_M} for medium load and V_{CS_L} for light load. In no load and ultra light load condition (NL mode), the current reference is also V_{CS_L} . But the operation in NL mode is different, which will be described in next section.

At constant current (CC) mode, the peak current is still V_{CS_H} when $V_O > V_{FB(SCP)}$, if not, the peak current is $2/3 * V_{CS_H}$.

It can be seen from the following figure that with multiple segment peak current control, AP3785T power system can keep switching frequency above 20kHz from light load to heavy load and guarantee the audible noise free performance, and the maximum system switching frequency is not less than 50kHz.

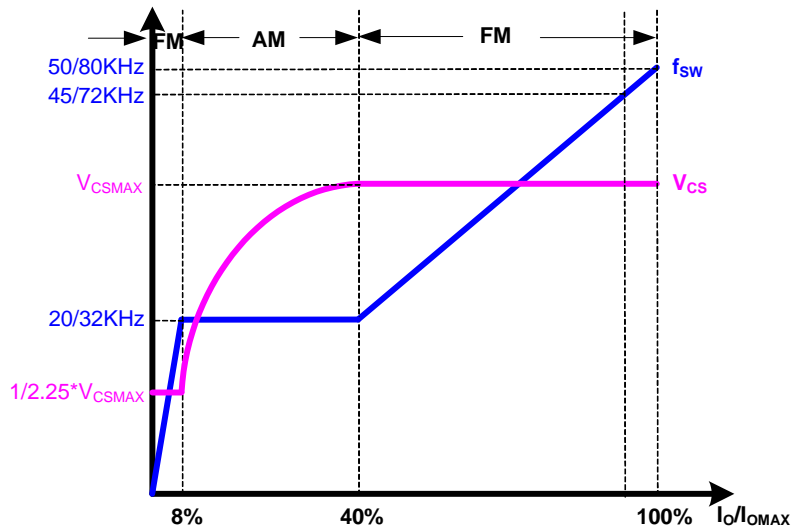


Figure 4. Segment Peak Current and Operating Frequency at CV Mode

6. Operating Frequency

For primary-side regulation, the primary current $i_p(t)$ is sensed by a current sense resistor R_{CS} (R_3 as shown in Typical Applications). The current rises up linearly at a rate of:

$$\frac{di_p(t)}{dt} = \frac{V_{IN}(t)}{L_M} \quad (6)$$

As illustrated in Figure 2, when the current $i_p(t)$ rises up to I_{PK} , the switch Q1 turns off. The constant peak current is given by:

$$I_{PK} = \frac{V_{CS}}{R_{CS}} \quad (7)$$

The energy stored in the magnetizing inductance L_M each cycle is therefore:

$$E_g = \frac{1}{2} \times L_M \cdot I_{PK}^2 \quad (8)$$

Operation Principle Description (Cont.)

So the power transferring from the input to the output is given by:

$$P = \frac{1}{2} \times L_M \times I_{PK}^2 \times f_{SW} \quad (9)$$

$$\eta \times \frac{1}{2} \times L_P \times I_{PK}^2 \times f_{SW} = P_O = V_O \times I_O \quad (10)$$

Where, f_{SW} is the switching frequency, η is the transferring efficiency.

In AP3785T, the high load mode and light load mode adopt the frequency modulation (FM), and the middle load mode uses the amplitude modulation (AM).

During FM, the peak current I_{PK} is constant, the output power depends on the switching frequency f_{SW} .

During AM, the frequency is fixed, V_{CS_M} is varied. Below is the analysis of V_{CS_M} .

The square root equation can be got from the following equation:

$$\eta \times \frac{1}{2} \times L_P \times I_{PK}^2 \times f_{SW} = \eta \times \frac{1}{2} \times L_P \times \left(\frac{V_{CS}}{R_{CS}} \right)^2 \times f_{SW} = V_O \times I_O \quad (11)$$

$$\text{So, } V_{CS} = \sqrt{\frac{2 \cdot R_{CS}^2 \cdot V_O \cdot I_O}{\eta \cdot L_P \cdot f_{SW}}} \quad (12)$$

During AM, the frequency is fixed, assume V_O and η are constants, then

$$V_{CS} = k \cdot \sqrt{I_O} \quad \left(k = \sqrt{\frac{2 \cdot R_{CS}^2 \cdot V_O}{\eta \cdot L_P \cdot f_{SW}}} \right) \quad (13)$$

7. NL Mode Operation (Typical Application with APR3415)

At no load and ultra light load, the AP3785T works at no load mode (NL mode) and the output voltage is detected by APR3415. In order to achieve ultra low standby power at NL mode, the static current is reduced to I_{CC_NL} .

- The conditions of exiting NL mode--- $V_{CBC} > V_{CBC(EN)}$ or $t_{OFF} < t_{OFF(EX)}$
- The conditions of entering NL mode-- $V_{CBC} < V_{CBC(EN)}$ and $t_{OFF} \geq t_{OFF(EN)}$

At NL mode, the internal reference voltage V_{DD} is pulled to ground. For normal NL working state, when the APR3415 detects the output voltage is lower than its trigger voltage. The APR3415 VDET pin emits a periodical pulse current. This pulse current will generate a pulse voltage on feedback winding through the transformer coupling. When the FB pin detects this pulse ($>V_{TRIGGER}$ is valid), the AP3785T re-establishes the V_{DD} and turns on primary switch to provide one energy pulse to supply output terminal and primary VCC voltage.

8. Leading Edge Blanking

When the power switch is turned on, a turn-on spike will occur on the sense-resistor. To avoid false-termination of the switching pulse, a leading-edge blanking (from power MOSFET on) is built in. During this blanking period, the current sense comparator is disabled and the gate driver can't be switched off.

9. Valley Turn-on

When the off time (t_{OFF}) is lower than t_{VAL-ON} , AP3785T power system can work with valley turn-on. It can reduce MOSFET switching on power losses which is resulted from the equivalent output capacitance to achieve highest overall efficiency. At the same time, because of valley turn-on the switching frequency has the random jitter feature, which will be benefit for conductive EMI performance. And valley turn-on can also reduce the power switch turn on spike current and then achieve the better radiative EMI performance.

Operation Principle Description (Cont.)

10. Adjustable Line Compensation

Since there is a constant delay time from the CS pin voltage reaching the given V_{CS} reference to the power MOSFET turning off, the real primary peak current value always has a gap with the ideal value. The gap value changes with different input line voltage, which is caused by different current rising slope, results in different system constant current value.

In order to eliminate the constant current deviation due to line voltage, the adjustable line compensation is introduced to design. The negative voltage of FB pin which is linear to the line voltage is added up to V_{CS} reference by a certain proportion and create an adjustable compensation voltage to clear up the primary current gap, so that the excellent line regulation of output current will be achieved.

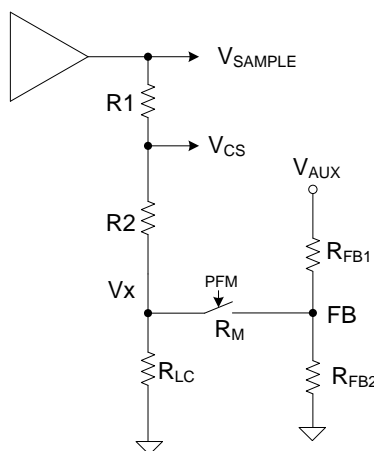


Figure 5. Adjustable Line Compensation Circuit

$$\Delta V_{CS} = -\frac{R_1}{R_1 + R_2} \cdot \frac{N_{AUX}}{N_P} \cdot \frac{R_{LC}}{R_{LC} + R_M + R_{FB1}} \cdot V_{LINE} \quad (14)$$

So, the AP3785T can change the line compensation capability by adjusting the upper resistor at FB pin (R_{FB1}). Higher resistance means lower line compensation capability.

11. Adjustable Cable Compensation

To meet the voltage drop of different output cables, the AP3785T can realize the adjustable cable compensation. As shown in Figure 6, V_{CBC} follows the V_{LOAD} that reflects the power system loading percentage.

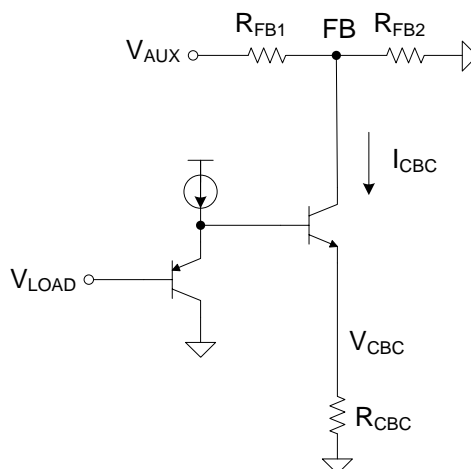


Figure 6. Adjustable Cable Compensation Circuit

Operation Principle Description (Cont.)

If the CBC resistance (R_{CBC}) and R_{FB1} are fixed, the current (I_{CBC}) flowing through the CBC resistance (R_{CBC}) also follows the changing of the V_{LOAD} :

$$I_{CBC} = \frac{V_{LOAD}}{R_{CBC}} \quad (15)$$

The voltage change (ΔV_{AUX}) of auxiliary winding (V_{AUX}) is varied with the V_{LOAD} :

$$\Delta V_{AUX} = R_{FB1} \cdot I_{CBC} = \frac{R_{FB1}}{R_{CBC}} \cdot V_{LOAD} \quad (16)$$

The V_O changing (ΔV_O) which ΔV_{AUX} reflects is also changed with V_{LOAD} :

$$\Delta V_O \approx \frac{N_S}{N_{AUX}} \cdot \Delta V_{AUX} = \frac{N_S}{N_{AUX}} \cdot \frac{R_{FB1}}{R_{CBC}} \cdot V_{LOAD} \quad (17)$$

So, the right cable compensation can be achieved by adjusting R_{CBC} . The 43k Ω resistance can ensure about 350mV cable compensation from no load to full load.

12. Protection

The AP3785T has multiple built-in fault protection functions: FB over voltage protection, VCC over voltage protection, output short circuit protection, FB open circuit protection, transformer saturation protection, current sense resistor fault (short or open) protection and external over temperature protection. The different fault conditions trigger the different protection modes.

Protection Mode

The AP3785T has three protection modes: Dmin, auto-recovery and fast auto-recovery, which the operation principles are different.

When FB down-resistance short protection is triggered, the AP3785T enters the Dmin mode whereby the AP3785T immediately shuts down and keeps a duration time $t_{OFF(MAX)}$ to output a pulse for turning on the primary switch, which is used to detect whether the fault condition is removed and provide VCC supply. If the fault condition is removed before V_{CC} decreases below $V_{OPR(MIN)}$, the device will enter normal operation mode. If not, the AP3785T will repeat another Dmin mode action. When V_{CC} drops below $V_{OPR(MIN)}$, AP3785T will enter the restart process, and VCC voltage changes between $V_{TH(ST)}$ and $V_{OPR(MIN)}$ until FB down-resistance short condition is removed.

When FB open circuit protection, output short circuit protection, transformer saturation protection and current sense resistor fault (short or open) protection are triggered, the device enters the auto-recovery mode. Once the AP3785T enters the auto-recovery mode, the device shuts down immediately and doesn't signal any pulse, the VCC static current is decreased from operating current (I_{CC_OPR}) to standby current (I_{CC_NL}). Until VCC voltage drops to $V_{OPR(MIN)}$, the AP3785T will enter the restart process, and VCC voltage changes between $V_{TH(ST)}$ and $V_{OPR(MIN)}$ until the fault condition is removed. The slope of VCC voltage to discharge is very small, and the time to drop to $V_{OPR(MIN)}$ is very long. It can decrease the average power dissipation at a fault condition.

When VCC over voltage protection, FB over voltage protection, CBC short to GND protection, internal over temperature and external over temperature protection are activated, the device enters the fast auto-recovery mode. The only difference with auto-recovery is that the VCC to discharge current is kept operating current and the system can fast restart.

12.1 Short Circuit Protection (SCP)

Short Circuit Protection (SCP) detection principle is similar to the normal output voltage feedback detection by sensing FB pin voltage. When the detected FB pin voltage is below $V_{FB(SCP)}$ for a duration of about t_{SCP} , the SCP is triggered. Then the AP3785T enters auto-recovery mode that the IC immediately shuts down and then restarts, so that the VCC voltage changes between V_{TH_ST} and UVLO threshold until $V_{FB(SCP)}$ condition is removed.

As to the normal system startup, the time duration of FB pin voltage below $V_{FB(SCP)}$ should be less than t_{SCP} to avoid entering SCP mode. But for the output short condition or the output voltage below a certain level, the SCP mode will be triggered.

Operation Principle Description (Cont.)

Figure 7 is the AP3785T normal start-up waveform that the voltage of FB pin is above $V_{FB(SCP)}$ during t_{SCP} after V_{CC} gets to the V_{TH_ST} , which doesn't enter the SCP mode. As shown in Figure 8, V_{OUT} is short and the voltage of FB pin is lower than $V_{FB(SCP)}$ during t_{SCP} , the AP3785T triggers the SCP and enters auto-recovery mode.

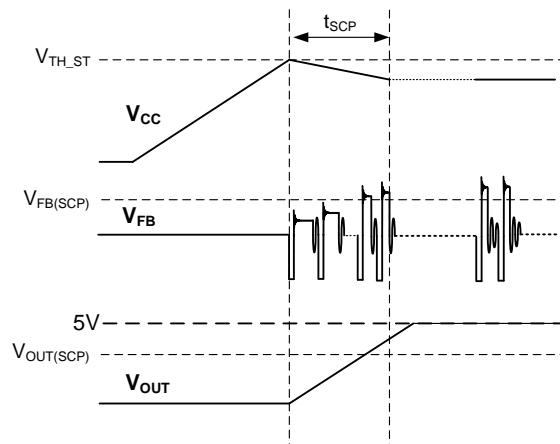


Figure 7. Normal Start-up

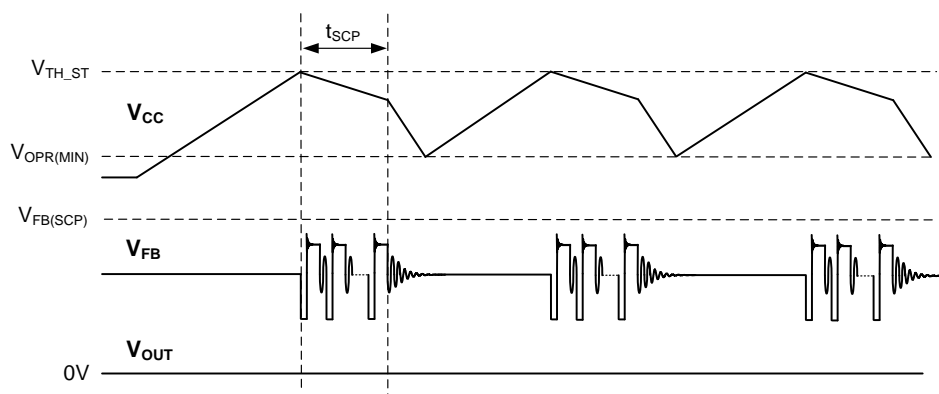


Figure 8. Short Circuit Protection (SCP) and Auto-recovery Mode

12.2 Transformer Saturation Protection via Primary Peak Current Limitation

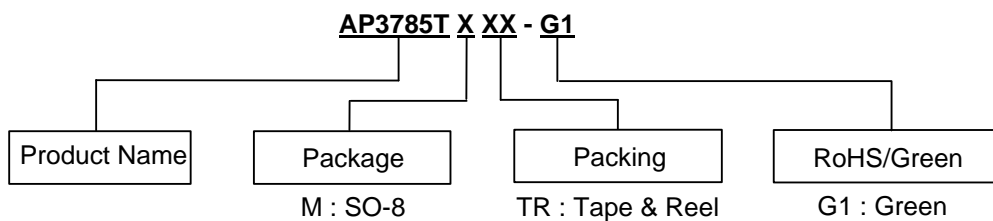
When the transformer saturation happens, the voltage of EM pin will increase promptly and be over the reference voltage $V_{EM(MAX)}$. If two consecutive pulses exceed the value, the device shuts down and enters into auto-recovery mode.

12.3 External Over Temperature Protection (External OTP)

The AP3785T provides external over-temperature protection (OTP) by connecting a Negative-Temperature-Coefficient (NTC) resistor from OTP pin to GND. Internally, a current source I_{OTP} is injected to the OTP pin, which generates a voltage proportional to the NTC resistance. At high ambient temperature, the NTC resistance gets lower and results in the OTP pin voltage decreasing. If the OTP pin voltage drops below an internally-set threshold V_{OTP} , then the OTP is triggered, and the AP3785T shuts down immediately and enters the fast auto-recovery mode. The power system will keep fast auto-recovery mode until the ambient temperature decreases and OTP pin voltage increases over the voltage V_{OTP_REC} , which the AP3785T can recover to normal operation.

If the OTP pin is not connected to the NTC resistor, the external OTP function will not work and the IC can still work normally with internal OTP.

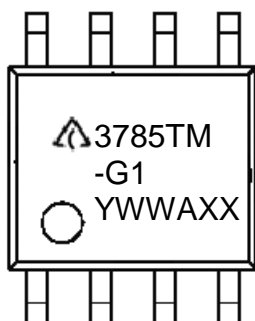
Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing
SO-8	-40 to +85°C	AP3785TMTR-G1	3785TM-G1	4000/Tape & Reel

Marking Information

(Top View)



First and Second Lines: Logo and Marking ID
 Third Line: Date Code
 Y: Year
 WW: Work Week of Molding
 A: Assembly House Code
 XX: 7th and 8th Digits of Batch No.

Technical drawing of a connector with dimensions and callouts for Option 1 and Option 2.

Top View:

- Overall width: 4.700(0.185)
- Distance from left edge to center of first pin: 5.100(0.201)
- Pin pitch: 1.270(0.050) TYP
- Pin diameter: 0.100(0.004)
- Distance from center of first pin to center of last pin: 0.300(0.012)
- Pin length: 1.350(0.053)
- Pin thickness: 1.750(0.069)
- Pin angle: 7° ~ 9°

Side View:

- Overall height: 0.600(0.024)
- Pin height: 0.725(0.029)
- Pin diameter: 0.320(0.013) TYP
- Pin angle: 8°
- Pin length: 5.800(0.228)
- Pin thickness: 6.200(0.244)
- Pin diameter: 0.320(0.013) TYP
- Pin angle: 8°
- Pin length: 5.800(0.228)
- Pin thickness: 6.200(0.244)

Option 1 Detail:

- Overall width: 1.000(0.039) TYP
- Pin pitch: 0.300(0.012)
- Pin length: 0.510(0.020)
- Pin diameter: 0.150(0.006)
- Pin thickness: 0.250(0.010)
- Pin angle: 0° / 8°
- Pin length: 0.450(0.017)
- Pin thickness: 0.820(0.032)
- Pin diameter: 0.320(0.013) TYP
- Pin angle: 8°
- Pin length: 5.800(0.228)
- Pin thickness: 6.200(0.244)

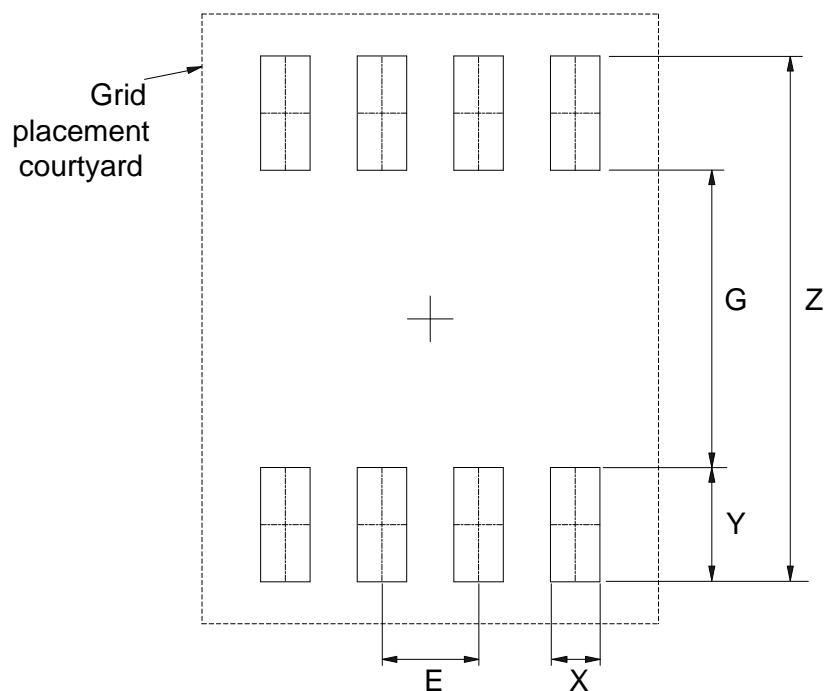
Option 2 Detail:

- Overall width: 0.350(0.014) TYP
- Pin pitch: 0.300(0.012)
- Pin length: 0.510(0.020)
- Pin diameter: 0.150(0.006)
- Pin thickness: 0.250(0.010)
- Pin angle: 0° / 8°
- Pin length: 0.450(0.017)
- Pin thickness: 0.820(0.032)
- Pin diameter: 0.320(0.013) TYP
- Pin angle: 8°
- Pin length: 5.800(0.228)
- Pin thickness: 6.200(0.244)

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Suggested Pad Layout

(1) Package Type: SO-8



Dimensions	Z (mm)/(inch)	G (mm)/(inch)	X (mm)/(inch)	Y (mm)/(inch)	E (mm)/(inch)
Value	6.900/0.272	3.900/0.154	0.650/0.026	1.500/0.059	1.270/0.050

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